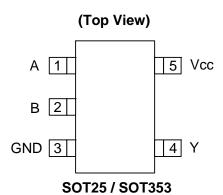


#### Description

The 74AHCT1G32 is a single 2-input positive OR gate with a standard totem pole output. The device is designed for operation with a power supply range of 4.5V to 5.5V. The gate performs the positive Boolean function:

$$Y = A + B \text{ or } Y = \overline{\overline{A} \bullet \overline{B}}$$

#### **Pin Assignments**



#### **Features**

- Supply Voltage Range from 4.5V to 5.5V
- ± 8 mA Output Drive at 5.0 V
- CMOS low power consumption
- Schmitt Trigger Action at All Inputs Make the Circuit Tolerant for Slower Input Rise and Fall Time.
- ESD Protection per JESD 22
  - Exceeds 200-V Machine Model (A115-A)
  - o Exceeds 2000-V Human Body Model (A114-A)
  - o Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- SOT25 and SOT353: Assembled with "Green" Molding Compound (no Br, Sb)
- Lead Free Finish / RoHS Compliant (Note 1)

#### **Applications**

- General Purpose Logic
- Wide array of products such as:
  - o PCs, networking, notebooks, netbooks, PDAs
  - o Computer peripherals, hard drives, CD/DVD ROM
  - TV, DVD, DVR, set top box
  - o Phones, Personal Navigation / GPS
  - MP3 players ,Cameras, Video Recorders

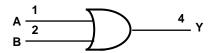
Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead\_free.html.



## **Pin Descriptions**

Pin Name	Pin No	Description
А	1	Data Input
В	2	Data Input
GND	3	Ground
Y	4	Data Output
V <sub>CC</sub>	5	Supply Voltage

# **Logic Diagram**



## **Function Table**

Inpi	Output	
Α	В	Υ
Н	Х	Н
Х	Н	Н
L	L	L



## **Absolute Maximum Ratings (Note 2)**

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	K۷
ESD MM	Machine Model ESD Protection	200	V
V <sub>CC</sub>	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage applied to output in high or low state	-0.5 to V <sub>CC</sub> +0.5	V
I <sub>IK</sub>	Input Clamp Current V <sub>I</sub> <0	-20	mA
I <sub>OK</sub>	Output Clamp Current (V <sub>O</sub> < 0 or V <sub>O</sub> > V <sub>CC</sub> )	±20	mA
Ιο	Continuous output current (V <sub>O</sub> = 0 to V <sub>CC</sub> )	±25	mA
I <sub>CC</sub>	Continuous current through V <sub>CC</sub>	50	mA
I <sub>GND</sub>	Continuous current through GND	-50	mA
TJ	Operating Junction Temperature	-40 to 150	°C
T <sub>STG</sub>	Storage Temperature	-65 to 150	°C

Notes: 2. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

## **Recommended Operating Conditions (Note 3)**

Symbol		Parameter	Min	Max	Unit
V <sub>CC</sub>	Operating Voltage		4.5	5.5	V
$V_{IH}$	High-level Input Voltage		2.0		V
V <sub>IL</sub>	Low-level input voltage			0.8	V
VI	Input Voltage		0	5.5	V
Vo	Output Voltage		0	$V_{CC}$	V
I <sub>OH</sub>	High-level output current			-8	mA
I <sub>OL</sub>	Low-level output current			8	mA
Δt/ΔV	Input transition rise or fall rate			20	ns/V
T <sub>A</sub>	Operating free-air temperature		-40	125	°C

Notes: 3. Unused inputs should be held at  $V_{\mbox{CC}}$  or Ground.



#### **Electrical Characteristics**

0	5	T O	.,		25°C		-40°C t	o 85°C	-40°C to	o 125ºC	11.24
Symbol	Parameter	Test Conditions	V <sub>CC</sub>	Min	Тур.	Max	Min	Max	Min	Max	Unit
.,	High Level	$I_{OH} = -50\mu A$	4.5V	4.4	4.5		4.4		4.4		.,
V <sub>OH</sub>	Output Voltage	$I_{OH} = -8mA$	4.5V	3.94			3.8		3.70		V
\/	Low Level	$I_{OL} = 50\mu A$	4.5V		0	0.1		0.1		0.1	V
V <sub>OL</sub>	Output Voltage	$I_{OL} = 8mA$	4.5V			0.36		0.44		0.55	V
l <sub>l</sub>	Input Current	$V_I = 5.5V$ or GND	0 to 5.5V			± 0.1		± 1		±2	μΑ
I <sub>CC</sub>	Supply Current	$V_I = 5.5V$ or GND $I_O=0$	5.5V			1		10		40	μΑ
C <sub>i</sub>	Input Capacitance	$V_I = V_{CC} - or$ GND	5.5V		2.0	10		10		10	pF
ΔI <sub>CC</sub>	Additional Supply Current	One input at 3.4 V Other inputs at V <sub>CC</sub> or GND	5.5V			1.35		1.5			mA
	Thermal Resistance	SOT25			204						0000
θ <sub>JA</sub> Junction-to- Ambient		SOT353	(Note 4)		371						°C/W
Thermal Resistance		SOT25	(Nata 4)		52						°C/W
$\theta_{JC}$	Junction-to- Case	SOT353	(Note 4)		143						C/VV

Note: 4. Test conditions for SOT25, and SOT353: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

## **Switching Characteristics**

 $V_{CC} = 5V \pm 0.5V$  (see Figure 1)

Parameter	From	TO			25°C		-40°C t	o 85ºC	-40°C to	125ºC	Unit
Parameter	(Input)	(OUTPUT)		Min	Тур.	Max	Min	Max	Min	Max	Offic
4	A or D	A == D	C <sub>L</sub> =15pF	0.6	3.3	6.9	0.6	8.0	0.6	9.0	ns
t <sub>pd</sub>	A or B	ř	C <sub>L</sub> =50pF	0.6	4.8	7.9	0.6	9.0	0.6	10.0	ns

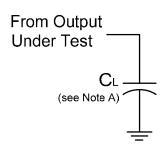
## **Operating Characteristics**

 $T_A = 25$  °C

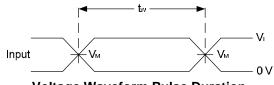
	Parameter	Test Conditions	V <sub>CC</sub> = 5 V Typ.	Unit
$C_pd$	Power dissipation capacitance	f = 1 MHz No Load	11.5	pF



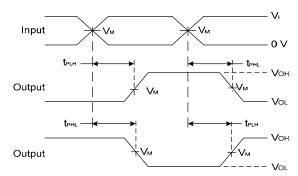
#### **Parameter Measurement Information**



V	In	puts	V	C	
V <sub>CC</sub>	VI	t <sub>r</sub> /t <sub>f</sub>	V <sub>M</sub>	CL	
5V±0.5V	3V	≤3ns	1.5V	15pF	
5V±0.5V	3V	≤3ns	1.5V	50pF	



**Voltage Waveform Pulse Duration** 



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Notes: A. Includes test lead and test apparatus capacitance.

B. All pulses are supplied at pulse repetition rate ≤ 1 MHz.

C. Inputs are measured separately one transition per measurement.

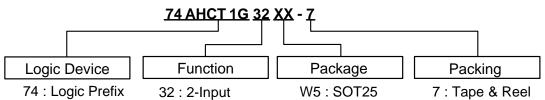
D. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.

**Pb**,



#### SINGLE 2 INPUT POSITIVE OR GATE

#### **Ordering Information**



AHCT: 2 to 5.5V

Family with TTL input level

1G: One gate

**Package** 7" Tape and Reel **Packaging Device** Code **Part Number Suffix** (Note 5) Quantity 74AHCT1G32W5-7 W5 SOT25 3000/Tape & Reel -7 74AHCT1G32SE-7 SE **SOT353** 3000/Tape & Reel -7

Notes: 5. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

4

OR-Gate

## Marking Information

#### (Top View)

XX Y W X

5

XX : Identification code

Y: Year 0~9

<u>W</u>: Week: A~Z: 1~26 week;

**SE: SOT353** 

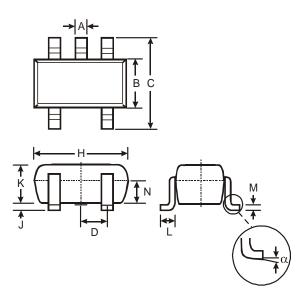
a~z: 27~52 week; z represents

Part Number	Package	Identification Code
74AHCT1G32W5	SOT25	ZW
74AHCT1G32SE	SOT353	ZW



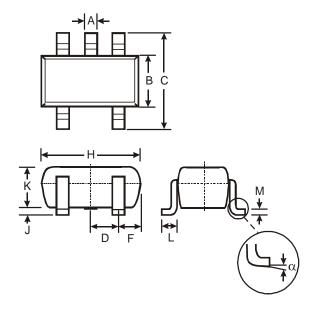
## Package Outline Dimensions (All Dimensions in mm)

## (1) Package Type: SOT25



	SOT25					
Dim	Min	Max	Тур			
Α	0.35	0.50	0.38			
В	1.50	1.70	1.60			
С	2.70	3.00	2.80			
D	_	_	0.95			
Н	2.90	3.10	3.00			
J	0.013	0.10	0.05			
K	1.00	1.30	1.10			
L	0.35	0.55	0.40			
M	0.10	0.20	0.15			
Ν	0.70	0.80	0.75			
α	0°	8°	_			
All D	imensi	ons in	mm			

#### (2) Package Type: SOT353



SOT353				
Dim	Min	Max		
Α	0.10	0.30		
В	1.15	1.35		
O	2.00	2.20		
D	0.65 Typ			
F	0.40	0.45		
H	1.80	2.20		
J	0	0.10		
K	0.90	1.00		
L	0.25	0.40		
М	0.10	0.22		
α	0°	8°		
All Dimensions in mm				



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